

SuperMOS – SOT-363 60V BV_{DSS}, 1.85Ω R_{DS(on)}, N-channel MOSFET

1. Description

The L2N7002DW1T1G-ES is N-Channel enhancement MOS Field Effect Transistor. Uses advanced technology and design to provide excellent R_{DS(ON)} with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product L2N7002DW1T1G-ES is Pb-free.

2. Features

- 60V, R_{DS(ON)}=1.85Ω(TYP.) @V_{GS}=10V
R_{DS(ON)}=2.05Ω(TYP.) @V_{GS}=4.5V
 - Use trench MOSFET technology
 - High density cell design for low R_{DS(on)}
 - ESD Protection - HBM : 2kV
- Material: Halogen free
 - Reliable and rugged
 - Avalanche Rated
 - Low leakage current

3. Applications

- PWM applications
 - Load switch
- Power management in portable/desktop PCs
 - DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
L2N7002DW1T1G-ES	SOT-363	.72KZ	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

5. Pin Configuration and Functions

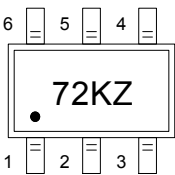
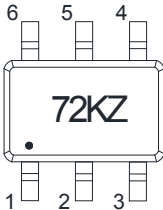
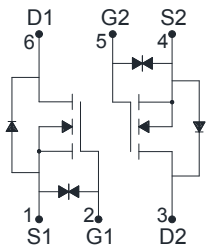
Pin	Function	Outline (POA)	Outline (POB)	Circuit Diagram
1	Source1	Note1 	Note1 	
2	Gate1			
6	Drain1			
4	Source2			
5	Gate2			
3	Drain2			

Table-2 Pin configuration

Note1:

This diagram is only an electrical schematic, and the actual pin size is based on POD

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_A=25^{\circ}\text{C}$	I_D	0.3	A
	$T_A=100^{\circ}\text{C}$		0.2	
Maximum Power Dissipation		P_D	350	mW
Pulsed Drain Current		I_{DM}	1.2	A
Operating Junction Temperature		T_J	150	°C
Lead Temperature		T_L	260	°C
Storage Temperature Range		T_{stg}	-55 to 150	°C

Thermal resistance ratings

Single Operation			
Parameter	Symbol	Typical	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	357	°C/W

L2N7002DW1T1G-ES

Rev-1.4

Electrical Characteristics

At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1.0	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±10	uA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =250uA	1.0	1.6	2.0	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =10V, I _D =0.3A		1.85	2.2	Ω
		V _{GS} =4.5V, I _D =0.2A		2.05	3.0	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, f=1MHz, V _{DS} =25V		28		pF
Output Capacitance	C _{OSS}			11		
Reverse Transfer Capacitance	C _{RSS}			4		
Total Gate Charge	Q _{G(TOT)}	V _{GS} =4.5V, V _{DS} =10V, I _D =0.3A		1.8		nC
Gate-to-Source Charge	Q _{GS}			0.3		
Gate-to-Drain Charge	Q _{GD}			0.6		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =10V, V _{DS} =10V, I _D =0.2A, R _G =10Ω		2		ns
Rise Time	t _r			15		
Turn-Off Delay Time	t _{d(OFF)}			7		
Fall Time	t _f			20		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =0.3A			1.5	V

7. Typical Characteristic

Figure 1: Output Characteristics

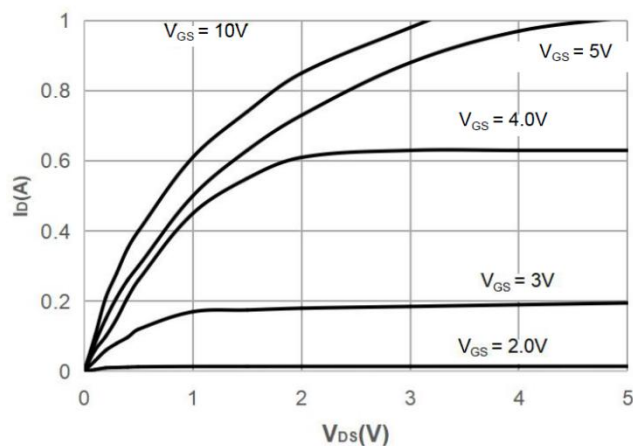


Figure 2: Typical Transfer Characteristics

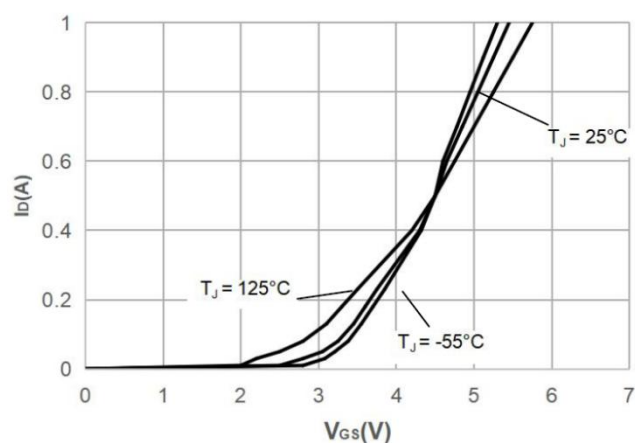


Figure 3: On-resistance vs. Drain Current

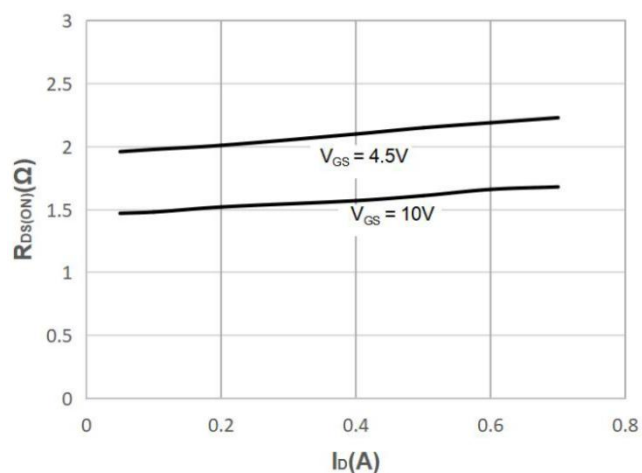


Figure 4: Body Diode Characteristics

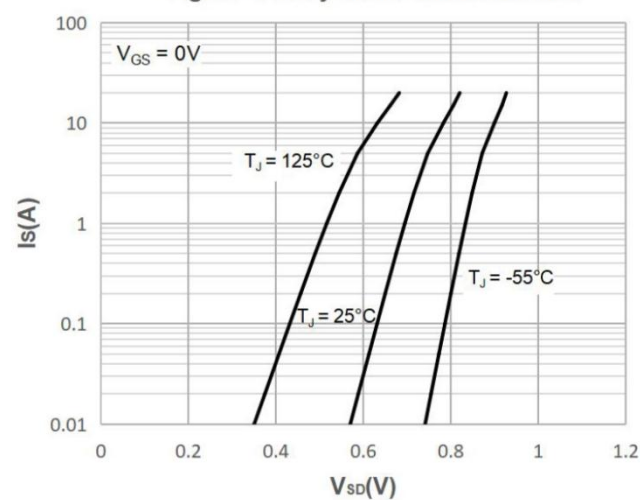


Figure 5: Gate Charge Characteristics

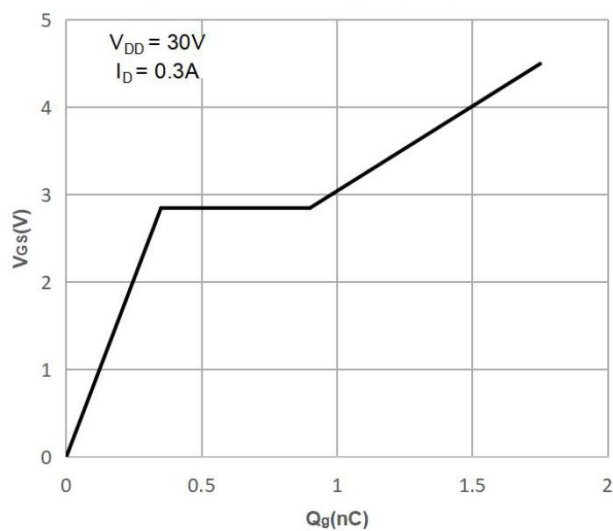


Figure 6: Capacitance Characteristics

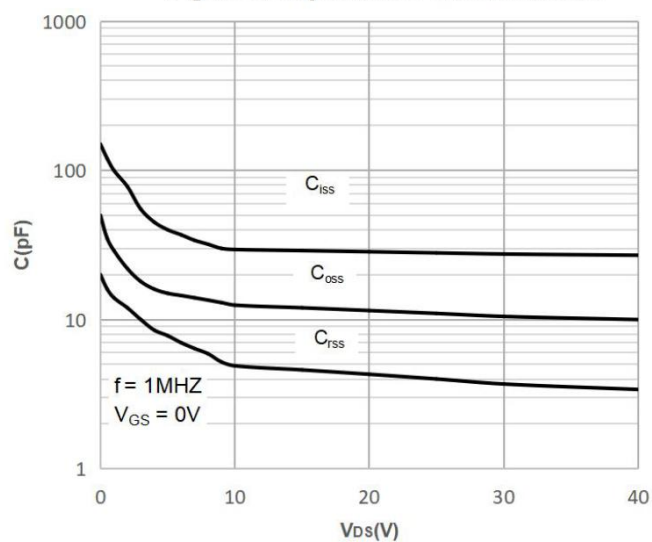


Figure 7: Normalized Breakdown voltage vs. Junction Temperature

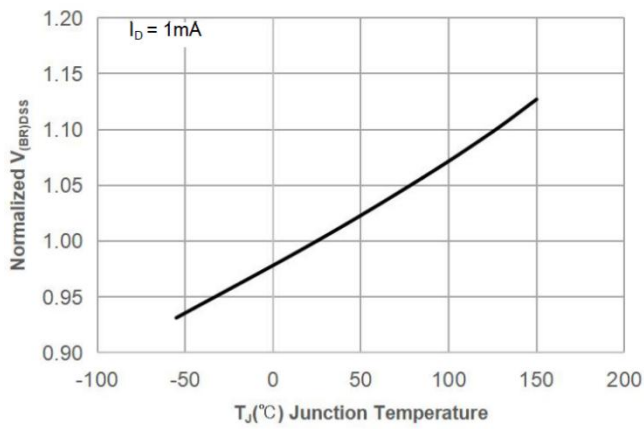


Figure 8: Normalized on Resistance vs. Junction Temperature

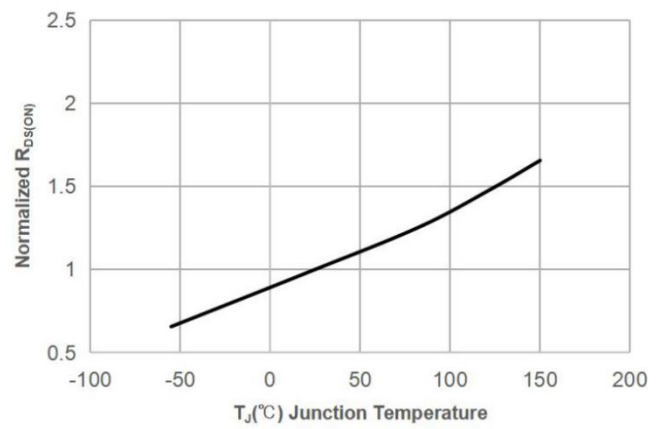


Figure 9: Maximum Safe Operating Area

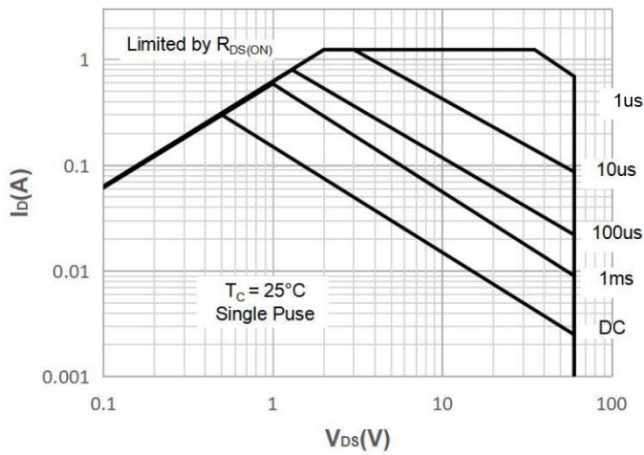


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

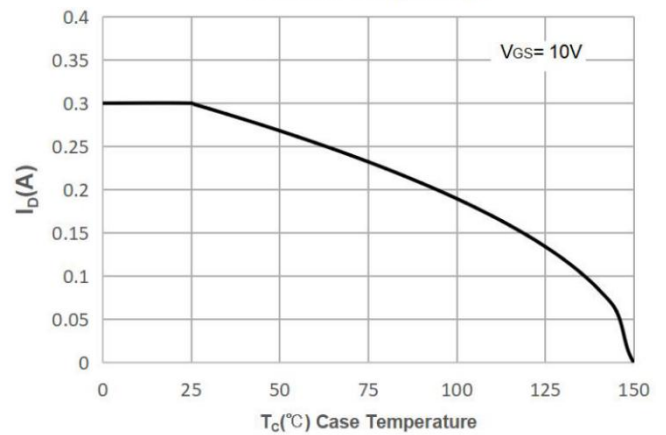


Figure 11: Normalized Maximum Transient Thermal Impedance

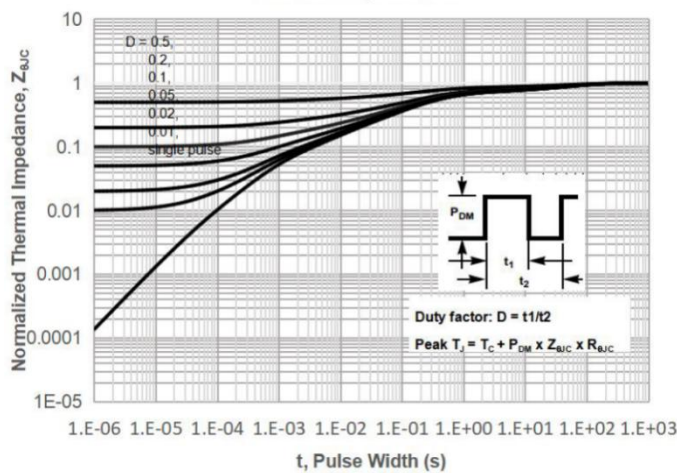
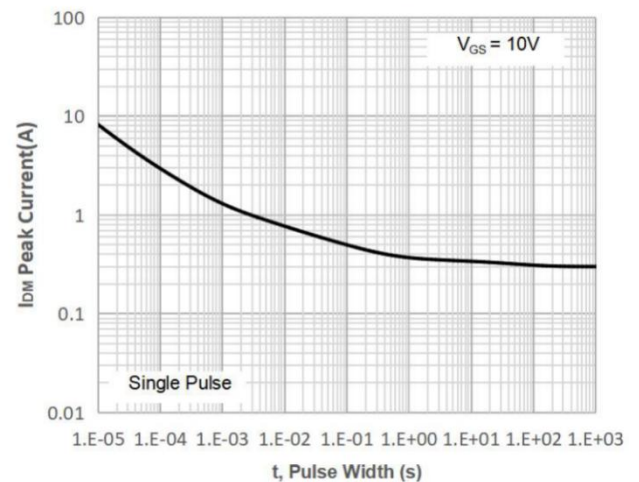
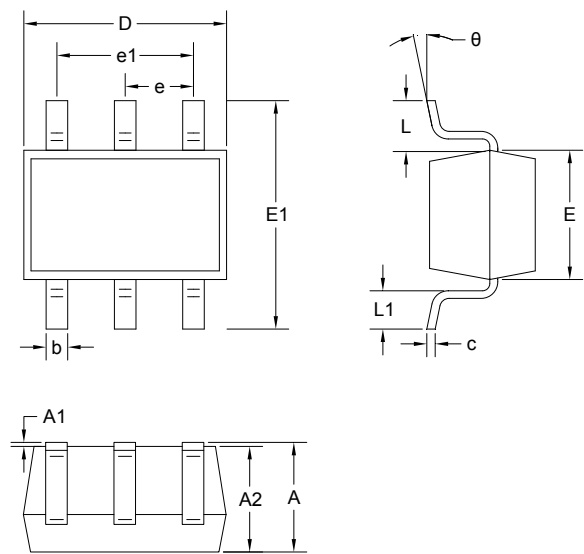


Figure 12: Peak Current Capacity



8. Dimension (SOT-363)-PODA



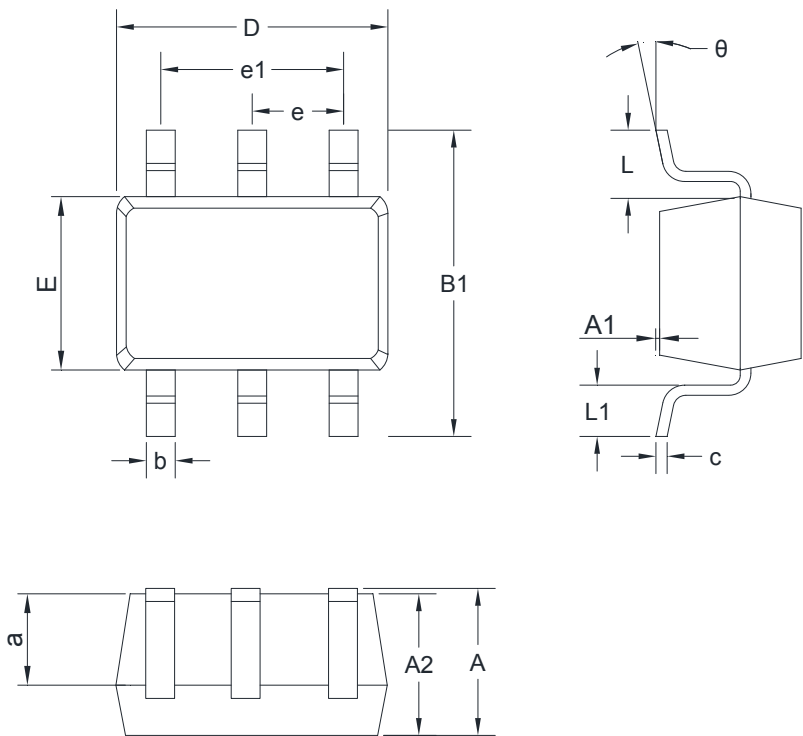
Unit: mm

Symbol		A	A1	A2	b	c	D	θ
Spec	Min	0.85	0	0.85	0.15	0.08	2.00	0°
	Max	1.05	0.10	0.95	0.35	0.15	2.20	8°
Symbol		E	E1	e	e1	L	L1	-
Spec	Min	1.15	2.10	0.650 REF	1.200	0.525 REF	0.2600	-
	Max	1.35	2.40		1.400		0.4600	-

L2N7002DW1T1G-ES

Rev-1.4

9. Dimension (SOT-363)-PODB



Dimensions in Millimeter					
SYMBOL	MIN	MAX	SYMBOL	MIN	MAX
A	0.9	1.1	E	1.15	1.35
A1	0.0	0.1	E1	2.15	2.45
A2	0.9	1.0	e	(0.65)	
D	2.0	2.2	e1	1.2	1.4
L1	0.26	0.46	θ	0°	8°
b	0.25	0.35	c	0.08	0.15
L	(0.525)		a	(0.45)	

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